

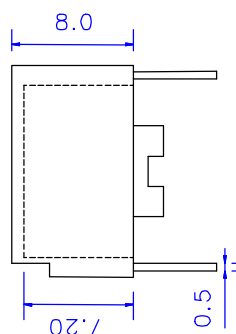
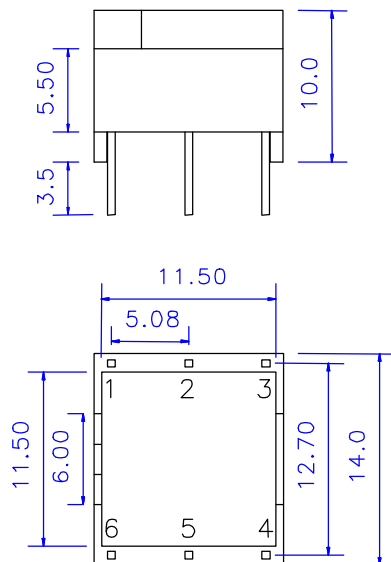
Feature

◆ Isolation Voltage : 3KVrms

◆ Designed for ISDN S-Interface

Specifications

Parameter	Condition		Min.	Typ.	Max.	Unit
Turns Ratio	Pin(4-6):(1-3)			1CT : 2CT		±2%
Inductance	@10KHz , 0.1V	Pin(4-6)	30			mH
Leakage Inductance	@100KHz , 0.1V	Pin(4-6) tie (1-3)			15.0	μH
C _{ww}	@10KHz , 0.1V				130	pF
CD Pri	@10KHz , 0.1V				50	pF
DC Resistance		Pin(4-6)			3.4+25%	Ω
		Pin(1-3)			5.4	Ω
Isolation Voltage	Pri. to Sec.		2000			Vrms
DC current					5	mA

Dimension


TOLERANCE: .XX±0.1
.X ±0.2

Schematic
